## NSN 5961-01-173-8209

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View Online at https://aerobasegroup.com/nsn/5961-01-173-8209 **Inclosure Material:** Plastic **Overall Length:** 0.615 inches **Overall Height:** 0.190 inches **Overall Width:** 0.420 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-220 **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 300.0 collector to base voltage/static/emitter open and 400.0 collector to emitter reverse voltage, with base short-circuited to emitter and 5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 2.00 amperes source cutoff current and 0.50 amperes source cutoff current **Power Rating Per Characteristic:** 2.1 watts small-signal input power, common-collector preset **Transfer Ratio:** 175.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

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